



LED Display

Product Data Sheet

LTP-7357JD

Spec No.: DS30-2000-416

Effective Date: 02/23/2001

Revision: -

LITE-ON DCC

RELEASE

FEATURES

- * 0.678 inch (17.22 mm) MATRIX HEIGHT.
- * LOW POWER REQUIREMENT.
- * SINGLE PLANE, WIDE VIEWING ANGLE.
- * SOLID STATE RELIABILITY.
- * 5×7 ARRAY WITH X-Y SELECT.
- * COMPATIBLE WITH USASCII AND EBCDIC CODES.
- * STACKABLE HORIZONTALLY.
- * CATEGORIZED FOR LUMINOUS INTENSITY.

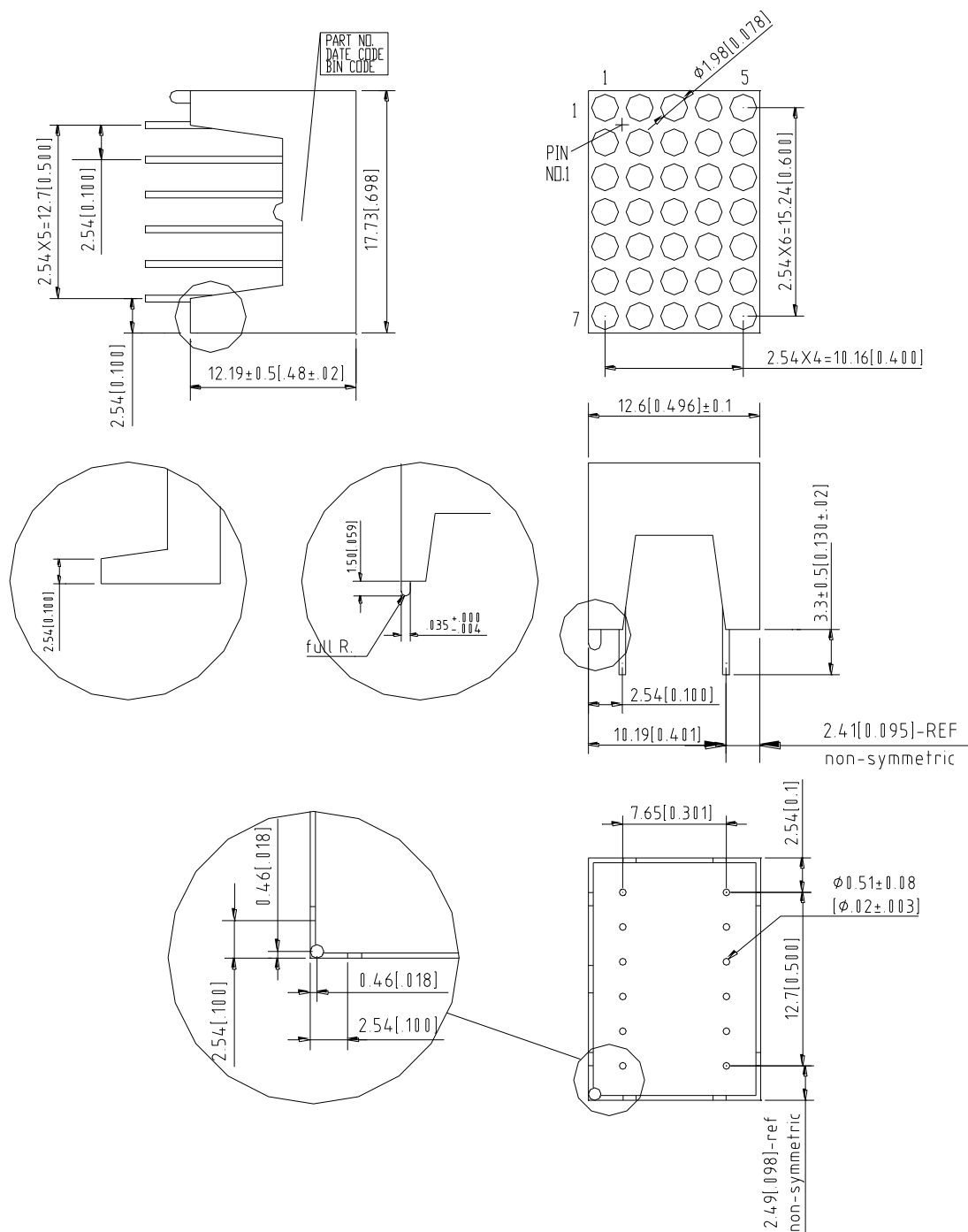
DESCRIPTION

The LTP-7357JD is a 0.678 inch (17.22 mm) matrix height 5×7 dot matrix display. This device utilizes ultra bright red LED chips, which are made from AlInGaP Hi.-Eff. Red on a non-transparent GaAs substrate, and has a gray face and white dot color.

DEVICE

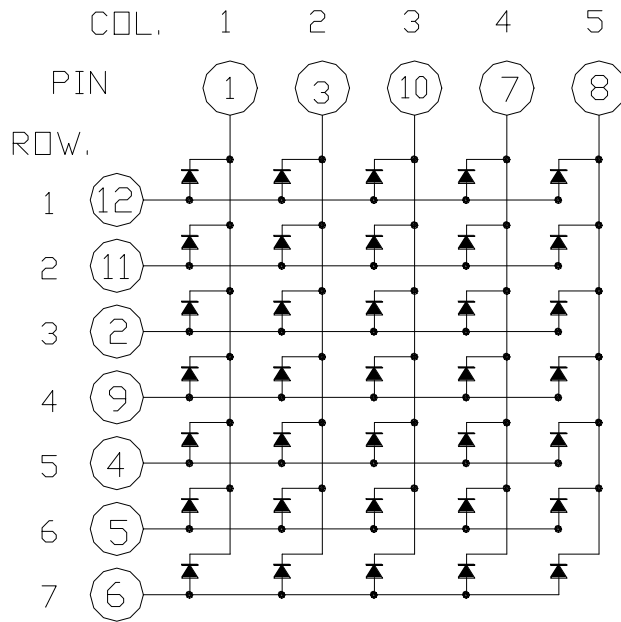
PART NO.	DESCRIPTION
AlInGaP HI.-EFF. RED	CATHODE COLUMN ANODE ROW
LTP-7357JD	

PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm (0.01 ") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



PIN CONNECTION

No.	CONNECTION
1	CATHODE COLUMN 1
2	ANODE ROW 3
3	CATHODE COLUMN 2
4	ANODE ROW 5
5	ANODE ROW 6
6	ANODE ROW 7
7	CATHODE COLUMN 4
8	CATHODE COUUMN 5
9	ANODE ROW 4
10	CATHODE COLUMN 3
11	ANODE ROW 2
12	ANODE ROW 1

ABSOLUTE MAXIMUM RATING AT Ta=25°C

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per Dot	33	mW
Peak Forward Current Per Dot	90	mA
Average Forward Current Per Dot	13	mA
Derating Linear From 25°C Per Dot	0.17	mA/°C
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm[1/16inch] below seating plane.		

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _v	500	1200		μcd	I _p =32mA 1/16Duty
Peak Emission Wavelength	λ _p		656		nm	I _F =20mA
Spectral Line Half-Width	Δλ		22		nm	I _F =20mA
Dominant Wavelength	λ _d		640		nm	I _F =20mA
Forward Voltage any Dot	V _F		2.1	2.6	V	I _F =20mA
Reverse Current any Dot	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio	I _v -m			1.8:1		I _p =32mA 1/16Duty

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

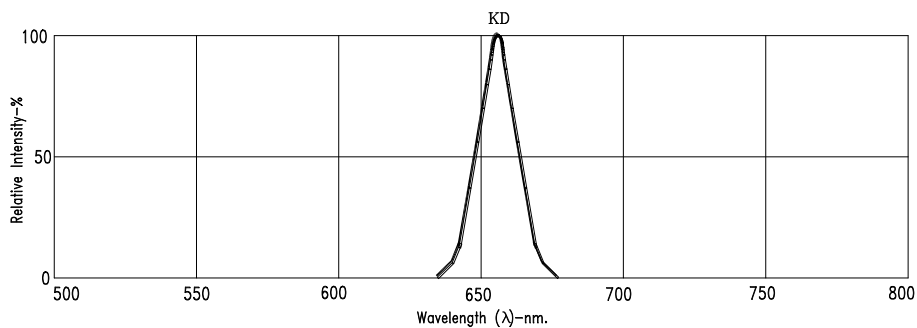


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

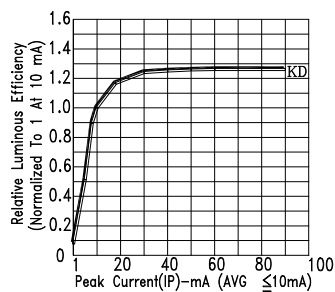


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT

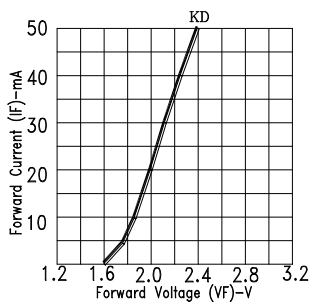


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

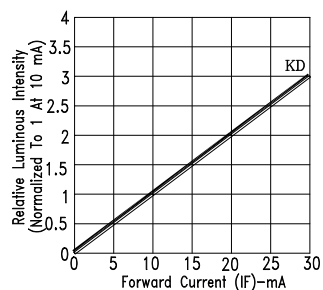


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

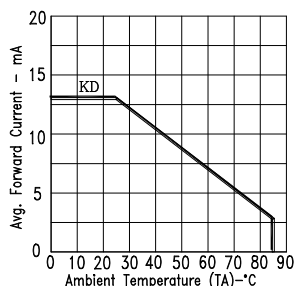


Fig5. MAX. AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE.

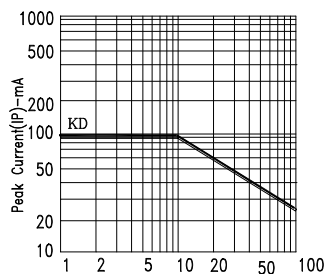


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE : KD=AlInGaP HL-EFF. RED